

L Number	Hits	Search Text	DB	Time stamp
1	401	gate with (metal or zirconium or zr or titanium or ti or hafnium or hf or lanthanum or la or gadolinium or gd or yttrium or y or aluminum or al or tungsten or w or tantalum or ta) with (silicon or silicate or si or silicide) with (oxygen or oxide or o) with (fluorine or fluoride or f)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/04/12 10:29
2	255	gate near2 (oxide or insulator or insulating or dielectric) with (metal or zirconium or zr or titanium or ti or hafnium or hf or lanthanum or la or gadolinium or gd or yttrium or y or aluminum or al or tungsten or w or tantalum or ta) with (silicon or silicate or si or silicide) with (oxygen or oxide or o) with (fluorine or fluoride or f)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/04/12 10:30
3	93	gate near2 (oxide or insulator or insulating or dielectric) with (metal or zirconium or zr or titanium or ti or hafnium or hf or lanthanum or la or gadolinium or gd or yttrium or y or aluminum or al or tungsten or w or tantalum or ta) with (silicon or silicate or si or silicide) with (oxygen or oxide or o) with (fluorine or fluoride or f) and gate near2 (insulator or insulating or dielectric or oxide) near5 (laminated or laminated or (plural or plurality or two or second or multiple or multiplicity or several or multi) near2 (layers or layered or films) or (layer or film) near3 (above or below or between or separating or top or bottom))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/04/12 10:33
4	15	gate near2 (oxide or insulator or insulating or dielectric) near8 (metal or zirconium or zr or titanium or ti or hafnium or hf or lanthanum or la or gadolinium or gd or yttrium or y or aluminum or al or tungsten or w or tantalum or ta) near3 (silicon or silicate or si or silicide) near3 (oxygen or oxide or o) near3 (fluorine or fluoride or f) and gate near2 (insulator or insulating or dielectric or oxide) near5 (laminated or laminated or (plural or plurality or two or second or multiple or multiplicity or several or multi) near2 (layers or layered or films) or (layer or film) near3 (above or below or between or separating or top or bottom))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/04/12 10:36
5	25	gate near2 (oxide or insulator or insulating or dielectric) near5 (metal or zirconium or zr or titanium or ti or hafnium or hf or lanthanum or la or gadolinium or gd or yttrium or y or aluminum or al or tungsten or w or tantalum or ta) near3 (silicon or silicate or si or silicide) near3 (oxygen or oxide or o) near3 (fluorine or fluoride or f)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/04/12 10:39
6	1371	gate near2 (oxide or insulator or insulating or dielectric) near5 (metal or zirconium or zr or titanium or ti or hafnium or hf or lanthanum or la or gadolinium or gd or yttrium or y or aluminum or al or tungsten or w or tantalum or ta) near3 (silicon or silicate or si or silicide) near3 (oxygen or oxide or o)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/04/12 10:39

7	176	gate near (oxide or insulator or insulating or dielectric) near2 (metal or zirconium or zr or titanium or ti or hafnium or hf or lanthanum or la or gadolinium or gd or yttrium or y or aluminum or al or tungsten or w or tantalum or ta) near2 (silicon or silicate or si or silicide) near2 (oxygen or oxide or o)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/04/12 10:55
8	230	gate near (oxide or insulator or insulating or dielectric) near2 (metal or zirconium or zr or titanium or ti or hafnium or hf or lanthanum or la or gadolinium or gd or yttrium or y or aluminum or al or tungsten or w or tantalum or ta) near (oxygen or oxide or o) near6 (silicon or si or silicate)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/04/12 10:56
9	1	gate near (oxide or insulator or insulating or dielectric) near2 (metal or zirconium or zr or titanium or ti or hafnium or hf or lanthanum or la or gadolinium or gd or yttrium or y or aluminum or al or tungsten or w or tantalum or ta) near (oxygen or oxide or o or oxynitride) near6 (silicon or si or silicate) near8 (fluorine or fluoride or f)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/04/12 10:57
10	99	gate near (oxide or insulator or insulating or dielectric) near (metal or zirconium or zr or titanium or ti or hafnium or hf or lanthanum or la or gadolinium or gd or yttrium or y or aluminum or al or tungsten or w or tantalum or ta) near (oxygen or oxide or o or oxynitride) near6 (silicon or si or silicate)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/04/12 11:49
11	593	257/411.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/04/12 11:46
12	283	257/411.ccls. and ((metal or zirconium or zr or titanium or ti or hafnium or hf or lanthanum or la or gadolinium or gd or yttrium or y or aluminum or al or tungsten or w or tantalum or ta) near (oxygen or oxide or o or oxynitride) or (zro or hfo or tio or lao or gdo or yo or alo or wo or tao))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/04/12 11:57
13	157	257/411.ccls. and ((metal or zirconium or zr or titanium or ti or hafnium or hf or lanthanum or la or gadolinium or gd or yttrium or y or aluminum or al or tungsten or w or tantalum or ta) near (oxygen or oxide or o or oxynitride) or (zro or hfo or tio or lao or gdo or yo or alo or wo or tao)) with (silicon or silicate or silicide or si)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/04/12 11:58
14	3	("6383873" "6407435" "6479404").PN.	USPAT	2004/04/12 12:13